

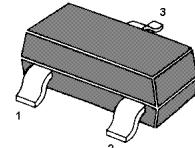
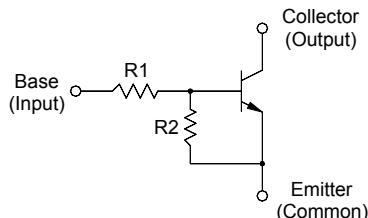
# MMBTRC116SS...MMBTRC122SS

## NPN Silicon Epitaxial Planar Transistor

for switching, interface circuit and drive circuit applications

### Features

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process



1. Base 2. Emitter 3. Collector  
SOT-23 Plastic Package

### Resistor Values

Type	R1 (KΩ)	R2 (KΩ)
MMBTRC116SS	1	10
MMBTRC117SS	2.2	2.2
MMBTRC118SS	2.2	10
MMBTRC119SS	4.7	10
MMBTRC120SS	10	4.7
MMBTRC121SS	47	10
MMBTRC122SS	100	100

### Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Parameter	Symbol	Value	Unit
Output Voltage	$V_O$	50	V
Input Voltage	MMBTRC116SS	10, - 5	V
	MMBTRC117SS	12, - 10	
	MMBTRC118SS	12, - 5	
	MMBTRC119SS	20, - 7	
	MMBTRC120SS	30, - 10	
	MMBTRC121SS	40, - 15	
	MMBTRC122SS	40, - 10	
Output Current	$I_O$	100	mA
Total Power Dissipation	$P_{tot}$	200	mW
Junction Temperature	$T_j$	150	°C
Storage Temperature Range	$T_{Stg}$	- 55 to + 150	°C

**TOP DYNAMIC**

# MMBTRC116SS...MMBTRC122SS

**Characteristics at  $T_a = 25^\circ\text{C}$**

Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at $V_o = 5\text{ V}$ , $I_o = 5\text{ mA}$ at $V_o = 5\text{ V}$ , $I_o = 20\text{ mA}$ at $V_o = 5\text{ V}$ , $I_o = 10\text{ mA}$ at $V_o = 5\text{ V}$ , $I_o = 10\text{ mA}$ at $V_o = 5\text{ V}$ , $I_o = 10\text{ mA}$ at $V_o = 5\text{ V}$ , $I_o = 5\text{ mA}$ at $V_o = 5\text{ V}$ , $I_o = 5\text{ mA}$	$G_I$	33	-	-	-
		20	-	-	-
		33	-	-	-
		30	-	-	-
		24	-	-	-
		33	-	-	-
		62	-	-	-
Output Cutoff Current at $V_o = 50\text{ V}$	$I_{O(OFF)}$	-	-	500	nA
Input Current at $V_i = 5\text{ V}$	$I_I$	-	-	7.2	mA
		-	-	3.8	
		-	-	3.8	
		-	-	1.8	
		-	-	0.88	
		-	-	0.16	
		-	-	0.15	
Output Voltage at $I_o = 10\text{ mA}$ , $I_I = 0.5\text{ mA}$ at $I_o = 10\text{ mA}$ , $I_I = 0.5\text{ mA}$ at $I_o = 10\text{ mA}$ , $I_I = 0.5\text{ mA}$ at $I_o = 10\text{ mA}$ , $I_I = 0.5\text{ mA}$ at $I_o = 10\text{ mA}$ , $I_I = 0.5\text{ mA}$ at $I_o = 10\text{ mA}$ , $I_I = 0.5\text{ mA}$ at $I_o = 5\text{ mA}$ , $I_I = 0.25\text{ mA}$	$V_{O(ON)}$	-	-	0.3	V
		-	-	0.3	
		-	-	0.3	
		-	-	0.3	
		-	-	0.3	
		-	-	0.3	
		-	-	0.3	
Input Voltage (ON) at $V_o = 0.3\text{ V}$ , $I_o = 20\text{ mA}$ at $V_o = 0.3\text{ V}$ , $I_o = 20\text{ mA}$ at $V_o = 0.3\text{ V}$ , $I_o = 20\text{ mA}$ at $V_o = 0.3\text{ V}$ , $I_o = 20\text{ mA}$ at $V_o = 0.3\text{ V}$ , $I_o = 2\text{ mA}$ at $V_o = 0.3\text{ V}$ , $I_o = 2\text{ mA}$ at $V_o = 0.3\text{ V}$ , $I_o = 1\text{ mA}$	$V_{I(ON)}$	-	-	3	V
		-	-	3	
		-	-	3	
		-	-	2.5	
		-	-	3	
		-	-	5	
		-	-	3	
Input Voltage (OFF) at $V_{CC} = 5\text{ V}$ , $I_o = 100\text{ }\mu\text{A}$	$V_{I(OFF)}$	0.3	-	-	V
		0.5	-	-	
		0.3	-	-	
		0.3	-	-	
		0.8	-	-	
		1	-	-	
		0.5	-	-	
Transition Frequency at $V_o = 10\text{ V}$ , $I_o = 5\text{ mA}$	$f_T^{(1)}$	-	250	-	MHz

<sup>(1)</sup> Characteristic of transistor only.